NSN 5961-01-131-0259

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-131-0259 **Inclosure Material:** Plastic **Overall Length:** 0.643 inches **Overall Height:** 0.135 inches **Overall Width:** 0.505 inches **End Application:** lp-1366 80009 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-127 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 4.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector absolute **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**